



March 2015

# FDP075N15A / FDB075N15A

## N-Channel PowerTrench<sup>®</sup> MOSFET

150 V, 130 A, 7.5 mΩ

### Features

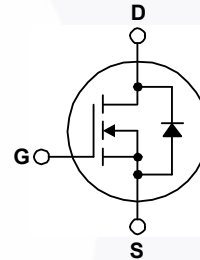
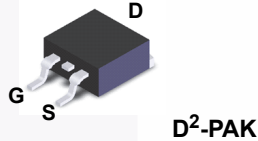
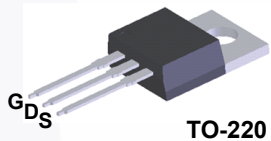
- $R_{DS(on)} = 6.25 \text{ m}\Omega$  (Typ.) @  $V_{GS} = 10 \text{ V}$ ,  $I_D = 100 \text{ A}$
- Fast Switching
- Low Gate Charge
- High Performance Trench Technology for Extremely Low  $R_{DS(on)}$
- High Power and Current Handling Capability
- RoHS Compliant

### Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench<sup>®</sup> process that has been tailored to minimize the on-state resistance while maintaining superior switching performance.

### Applications

- Synchronous Rectification for ATX / Server / Telecom PSU
- Battery Protection Circuit
- Motor Drives and Uninterruptible Power Supplies
- Micro Solar Inverter



### MOSFET Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	FDP075N15A_F102 FDB075N15A	Unit
$V_{DSS}$	Drain to Source Voltage	150	V
$V_{GSS}$	Gate to Source Voltage	- DC	$\pm 20$
		- AC (f > 1 Hz)	$\pm 30$
$I_D$	Drain Current	- Continuous ( $T_C = 25^\circ\text{C}$ )	130*
		- Continuous ( $T_C = 100^\circ\text{C}$ )	92
$I_{DM}$	Drain Current	- Pulsed (Note 1)	522
$E_{AS}$	Single Pulsed Avalanche Energy	(Note 2)	588
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	6.0
$P_D$	Power Dissipation	( $T_C = 25^\circ\text{C}$ )	333
		- Derate Above $25^\circ\text{C}$	2.22
$T_J, T_{STG}$	Operating and Storage Temperature Range	-55 to +175	$^\circ\text{C}$
$T_L$	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds	300	$^\circ\text{C}$

\* Package limitation current is 120 A.

### Thermal Characteristics

Symbol	Parameter	FDP075N15A_F102 FDB075N15A	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	0.45	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Minimum Pad of 2-oz Copper), Max.	62.5	
	Thermal Resistance, Junction to Ambient, D2-PAK (1 in <sup>2</sup> Pad of 2-oz Copper), Max.	40	

## Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FDP075N15A_F102	FDP075N15A	TO-220	Tube	N/A	N/A	50 units
FDB075N15A	FDB075N15A	D <sup>2</sup> -PAK	Tape and Reel	330 mm	24 mm	800 units

## Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
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### Off Characteristics

$BV_{DSS}$	Drain to Source Breakdown Voltage	$I_D = 250 \mu\text{A}, V_{GS} = 0 \text{ V}$	150	-	-	V
$\Delta BV_{DSS} / \Delta T_J$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu\text{A}$ , Referenced to $25^\circ\text{C}$	-	0.1	-	V/ $^\circ\text{C}$
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = 120 \text{ V}, V_{GS} = 0 \text{ V}$ $V_{DS} = 120 \text{ V}, T_C = 150^\circ\text{C}$	-	-	1 500	$\mu\text{A}$
$I_{GSS}$	Gate to Body Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	-	-	$\pm 100$	nA

### On Characteristics

$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu\text{A}$	2.0	-	4.0	V
$R_{DS(on)}$	Static Drain to Source On Resistance	$V_{GS} = 10 \text{ V}, I_D = 100 \text{ A}$	-	6.25	7.5	m $\Omega$
$g_{FS}$	Forward Transconductance	$V_{DS} = 10 \text{ V}, I_D = 100 \text{ A}$	-	164	-	S

### Dynamic Characteristics

$C_{iss}$	Input Capacitance	$V_{DS} = 75 \text{ V}, V_{GS} = 0 \text{ V},$ $f = 1 \text{ MHz}$	-	5525	7350	pF
$C_{oss}$	Output Capacitance		-	516	685	pF
$C_{riss}$	Reverse Transfer Capacitance		-	21	-	pF
$C_{oss(er)}$	Energy Related Output Capacitance	$V_{DS} = 75 \text{ V}, V_{GS} = 0 \text{ V}$	-	909	-	pF
$Q_{g(tot)}$	Total Gate Charge at 10V	$V_{DS} = 75 \text{ V}, I_D = 100 \text{ A},$ $V_{GS} = 10 \text{ V}$	-	77	100	nC
$Q_{gs}$	Gate to Source Gate Charge		-	26	-	nC
$Q_{gs2}$	Gate Charge Threshold to Plateau		-	11	-	nC
$Q_{gd}$	Gate to Drain "Miller" Charge		(Note 4)	-	16	-
ESR	Equivalent Series Resistance(G-S)	$f = 1 \text{ MHz}$	-	2.29	-	$\Omega$

### Switching Characteristics

$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = 75 \text{ V}, I_D = 100 \text{ A},$ $V_{GS} = 10 \text{ V}, R_G = 4.7 \Omega$	-	28	66	ns
$t_r$	Turn-On Rise Time		-	37	84	ns
$t_{d(off)}$	Turn-Off Delay Time		-	62	134	ns
$t_f$	Turn-Off Fall Time		(Note 4)	-	21	52

### Drain-Source Diode Characteristics

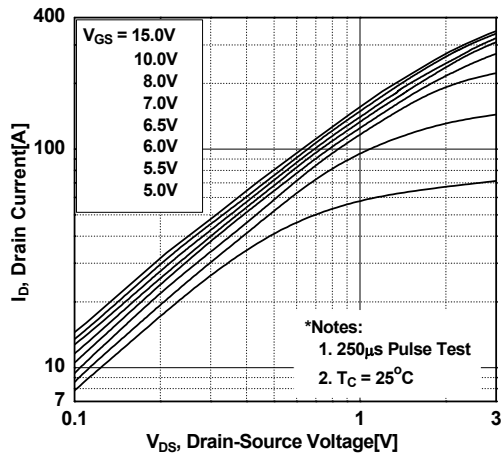
$I_S$	Maximum Continuous Drain to Source Diode Forward Current	-	-	130*	A	
$I_{SM}$	Maximum Pulsed Drain to Source Diode Forward Current	-	-	520	A	
$V_{SD}$	Drain to Source Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_{SD} = 100 \text{ A}$	-	-	1.25	V
$t_{rr}$	Reverse Recovery Time	$V_{GS} = 0 \text{ V}, V_{DD} = 75 \text{ V}, I_{SD} = 100 \text{ A},$	-	97	-	ns
$Q_{rr}$	Reverse Recovery Charge	$di_F/dt = 100 \text{ A}/\mu\text{s}$	-	264	-	nC

#### Notes:

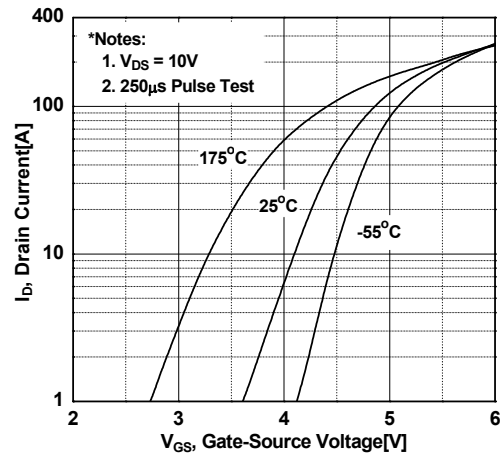
1. Repetitive rating: pulse-width limited by maximum junction temperature.
2. Starting  $T_J = 25^\circ\text{C}$ ,  $L = 3 \text{ mH}$ ,  $I_{AS} = 19.8 \text{ A}$ .
3.  $I_{SD} \leq 100 \text{ A}$ ,  $di/dt \leq 200 \text{ A}/\mu\text{s}$ ,  $V_{DD} \leq BV_{DSS}$ , starting  $T_J = 25^\circ\text{C}$ .
4. Essentially independent of operating temperature typical characteristics.

## Typical Performance Characteristics

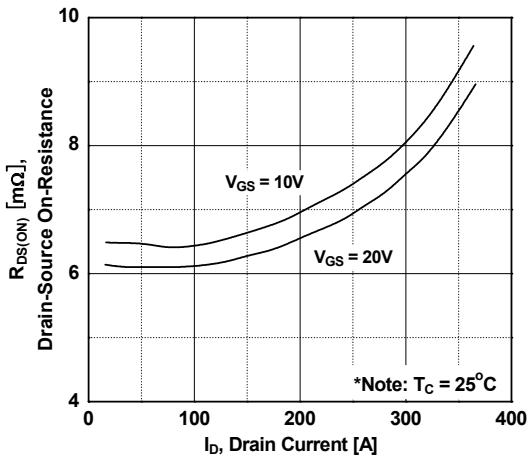
**Figure 1. On-Region Characteristics**



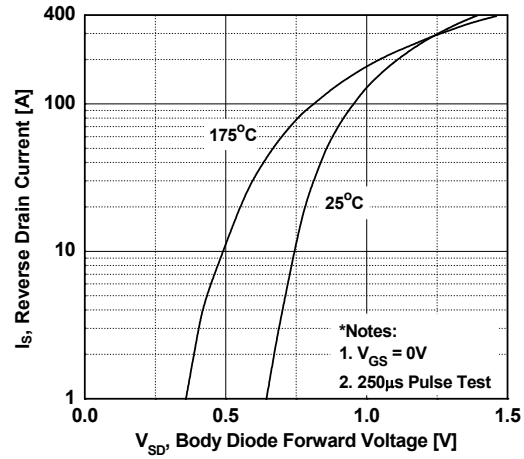
**Figure 2. Transfer Characteristics**



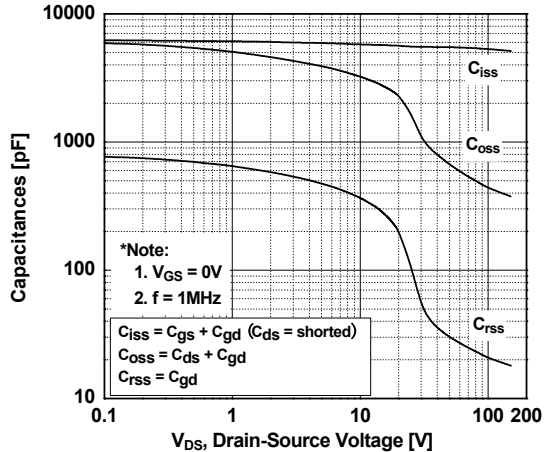
**Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage**



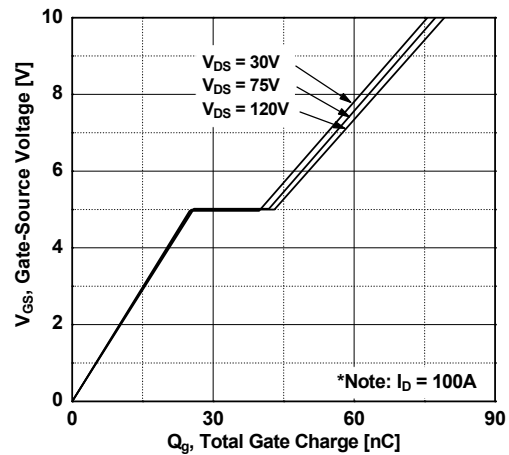
**Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature**



**Figure 5. Capacitance Characteristics**

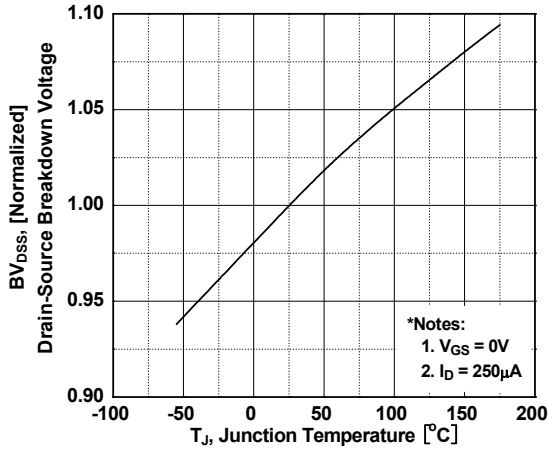


**Figure 6. Gate Charge Characteristics**

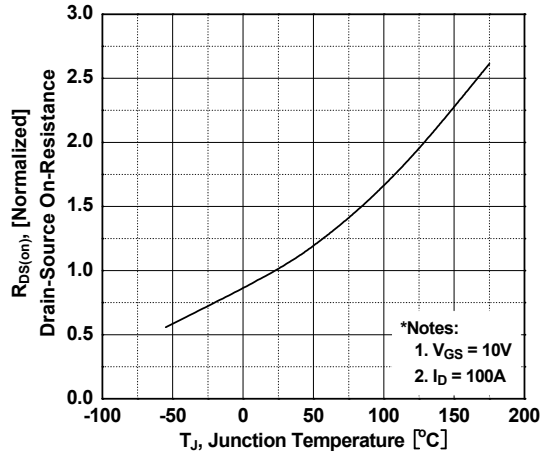


**Typical Performance Characteristics** (Continued)

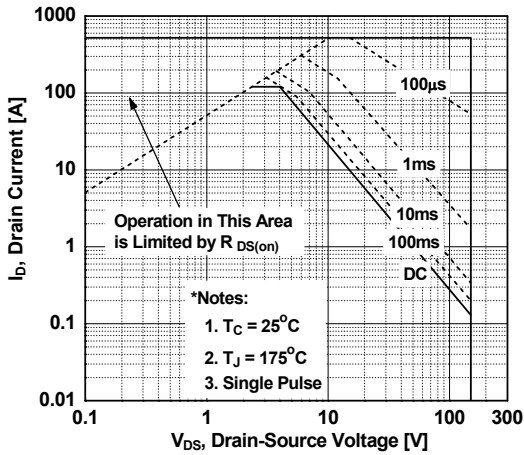
**Figure 7. Breakdown Voltage Variation vs. Temperature**



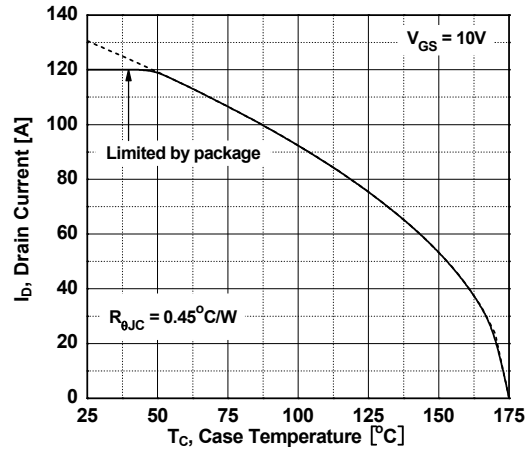
**Figure 8. On-Resistance Variation vs. Temperature**



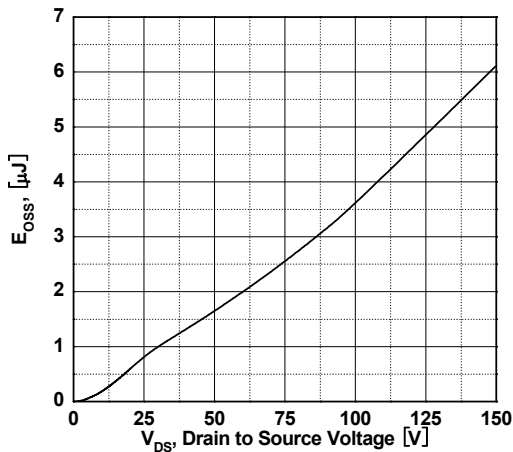
**Figure 9. Maximum Safe Operating Area**



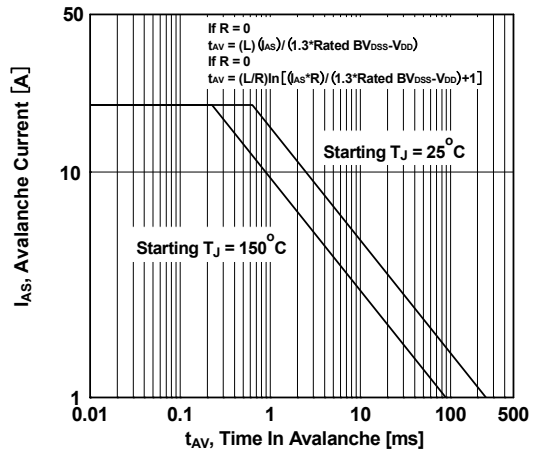
**Figure 10. Maximum Drain Current vs. Case Temperature**



**Figure 11. E\_oss vs. Drain to Source Voltage**

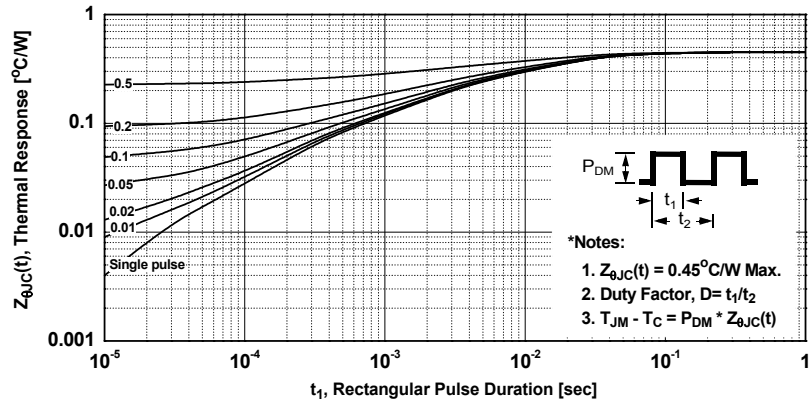


**Figure 12. Unclamped Inductive Switching Capability**



Typical Performance Characteristics (Continued)

Figure 13. Transient Thermal Response Curve





**Figure 14. Gate Charge Test Circuit & Waveform**



**Figure 15. Resistive Switching Test Circuit & Waveforms**

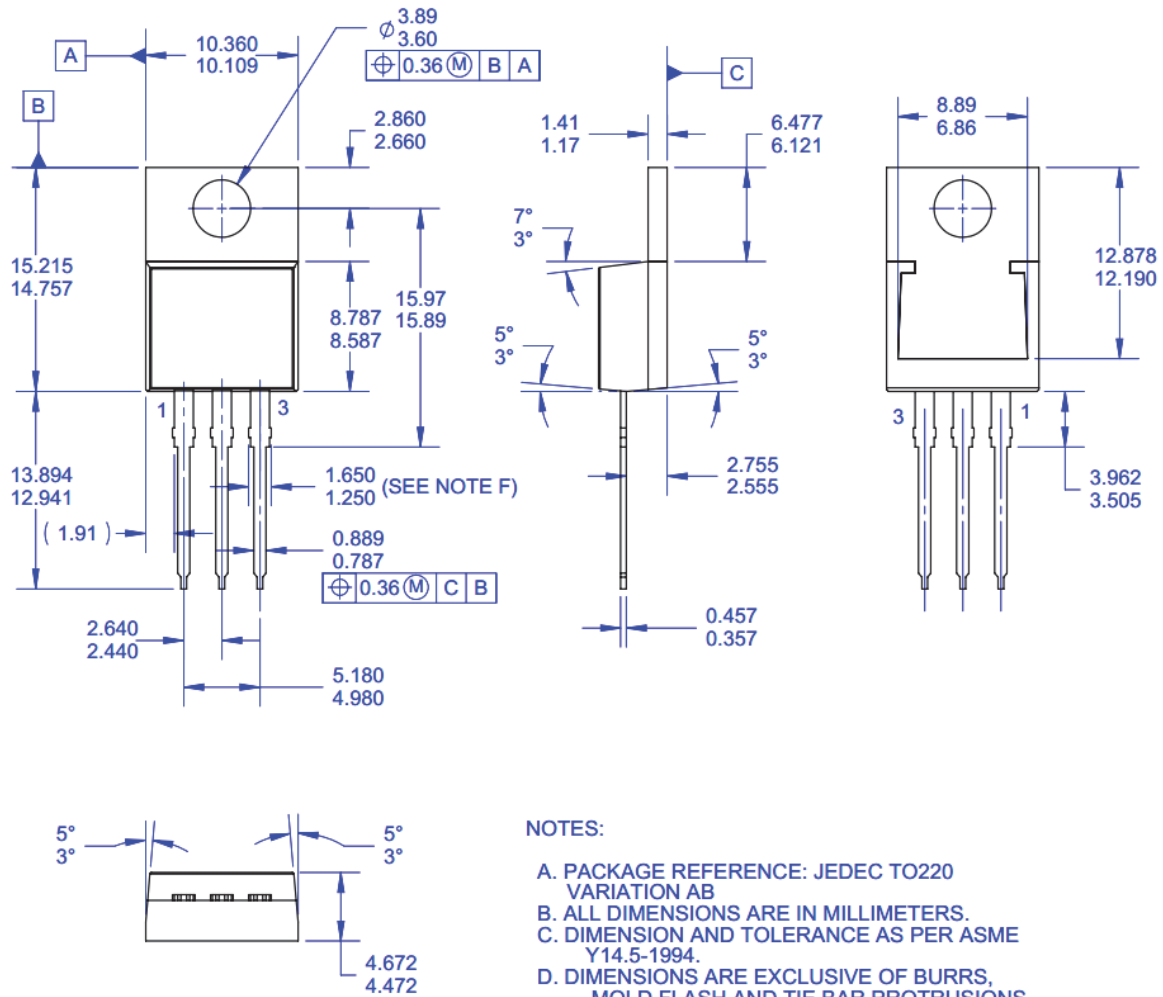


**Figure 16. Unclamped Inductive Switching Test Circuit & Waveforms**



Figure 17. Peak Diode Recovery  $dv/dt$  Test Circuit & Waveforms

## Mechanical Dimensions



**Figure 18. TO-220, Molded, 3-Lead, Jedec Variation AB (Delta)**

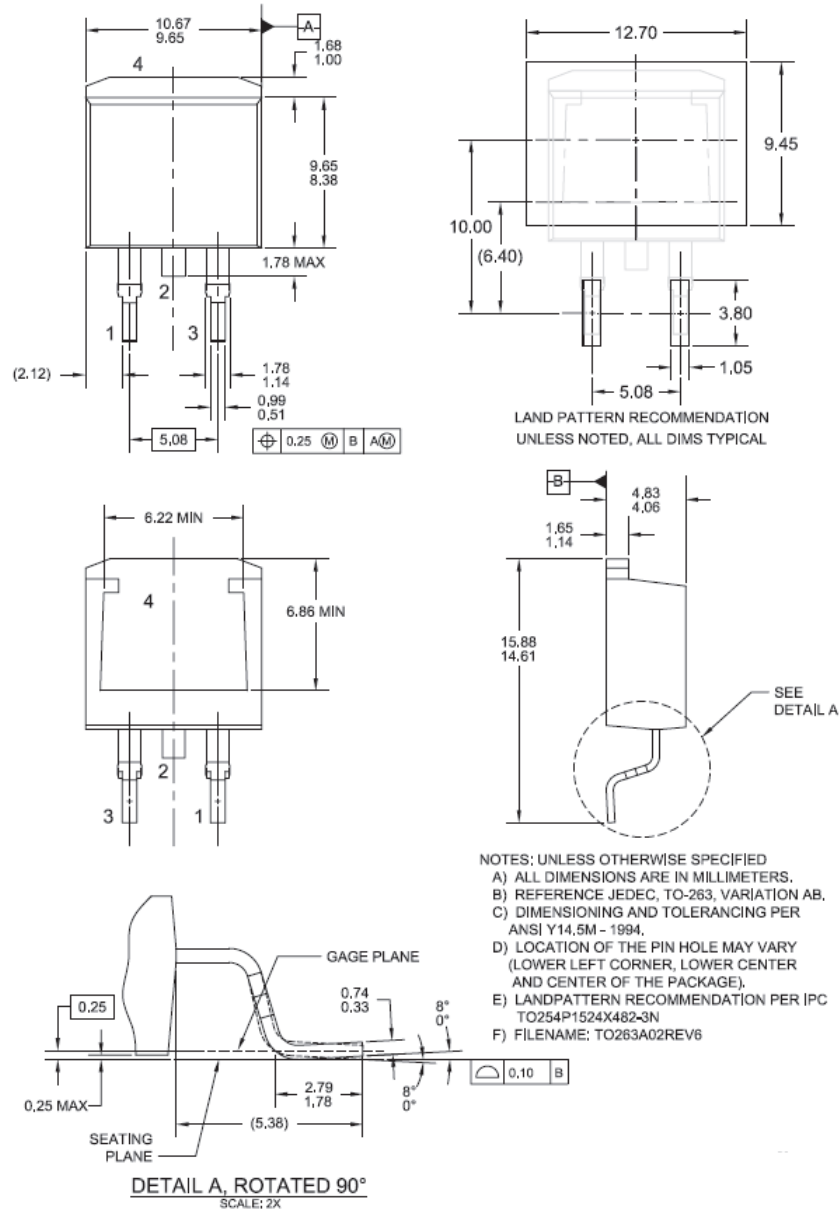
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## Mechanical Dimensions



**Figure 19. TO263 (D<sup>2</sup>PAK), Molded, 2-Lead, Surface Mount**

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|   |   |                                    | TinyBuck®   |
|   |   |                                    | TinyCalc™   |
|   |   |                                    | TinyLogic®  |
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|   |   |                                    | TinyPower™  |
|   |   |                                    | TinyPWM™  |
|   |   |                                    | TinyWire™   |
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|   |   |                                    |  |
|   |   |                                    | UHC®  |
|   |   |                                    | Ultra FRFET™  |
|   |   |                                    | UniFET™   |
|   |   |                                    | VCX™  |
|   |   |                                    | VisualMax™  |
|   |   |                                    | VoltagePlus™  |
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